**Product data sheet** 

# 1. General description

Enhanced ultrafast power diode in a TO252 (DPAK) surface-mountable plastic package.

## 2. Features and benefits

- · High thermal cycling performance
- Low on-state losses
- · Low thermal resistance
- Soft recovery characteristic
- Surface-mountable package

# 3. Applications

- Dual mode (DCM and CCM) Power Factor Correction (PFC)
- Power Factor Correction (PFC) for Interleaved Topology
- U-inverter (DC-AC converter for individual solar panels)

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>R</sub>	reverse voltage	DC	-	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 115 °C; square-wave pulse; Fig. 1; Fig. 2	-	-	9	Α
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 µs; $T_{mb} \le 115$ °C; square-wave pulse	-	-	18	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	-	91	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	-	100	Α
Static chara	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.45	1.9	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C	-	1.25	1.7	V
Dynamic ch	aracteristics					
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 6$	-	17.5	35	ns

# 5. Pinning information

## **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	L mp	K — A
2	K	cathode[1]		001aaa020
3	Α	anode		
mb	К	mounting base; connected to cathode	DPAK (TO252N)	

<sup>[1]</sup> It is not possible to connect to pin 2 of the SOT428 package.

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package					
	Name	Description	Version			
BYV29FD-600	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	TO252N			

# 7. Limiting values

### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
$V_{RWM}$	crest working reverse voltage		-	600	V
$V_R$	reverse voltage	DC	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 115 °C; square-wave pulse; Fig. 1; Fig. 2	-	9	Α
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 $\mu$ s; $T_{mb} \le 115$ °C; square-wave pulse	-	18	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	91	А
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	100	Α
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>j</sub>	junction temperature		-	150	°C

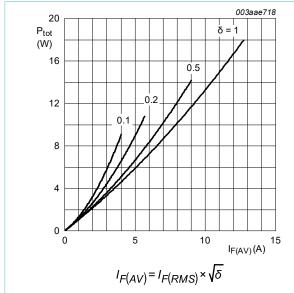


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

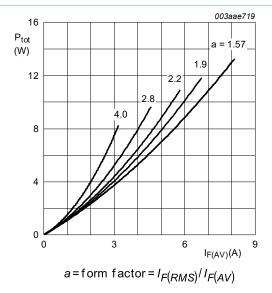


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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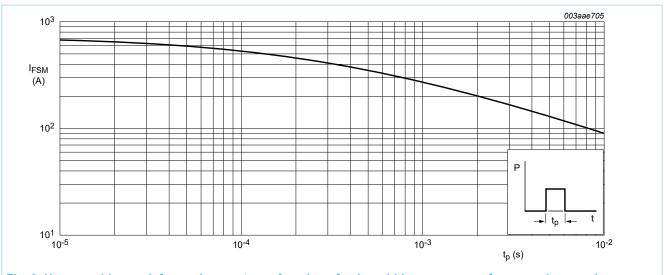


Fig. 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

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## 8. Thermal characteristics

**Table 5. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 4	-	-	2.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

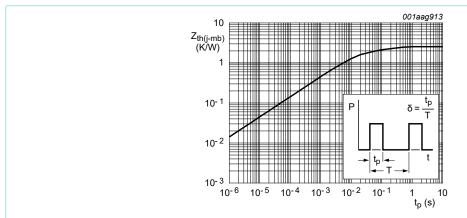
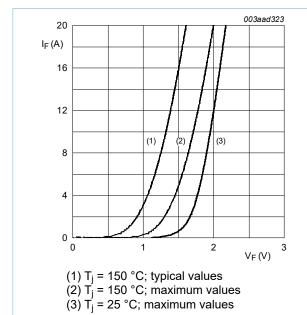


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse width

## 9. Characteristics

### **Table 6. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.45	1.9	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C	-	1.25	1.7	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 100 °C	-	-	1.5	mA
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	50	μΑ
Dynamic ch	naracteristics			'		
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; Fig. 6	-	17.5	35	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; Fig. 6	-	1.5	-	Α
Q <sub>r</sub>	recovered charge		-	13	-	nC
$V_{FR}$	forward recovery voltage	$I_F = 1 \text{ A}; dI_F/dt = 100 \text{ A/}\mu\text{s}; Fig. 6$	-	3.2	-	V





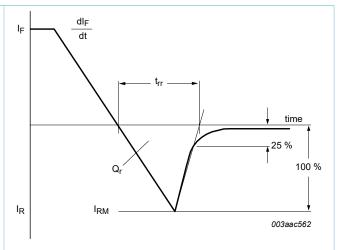
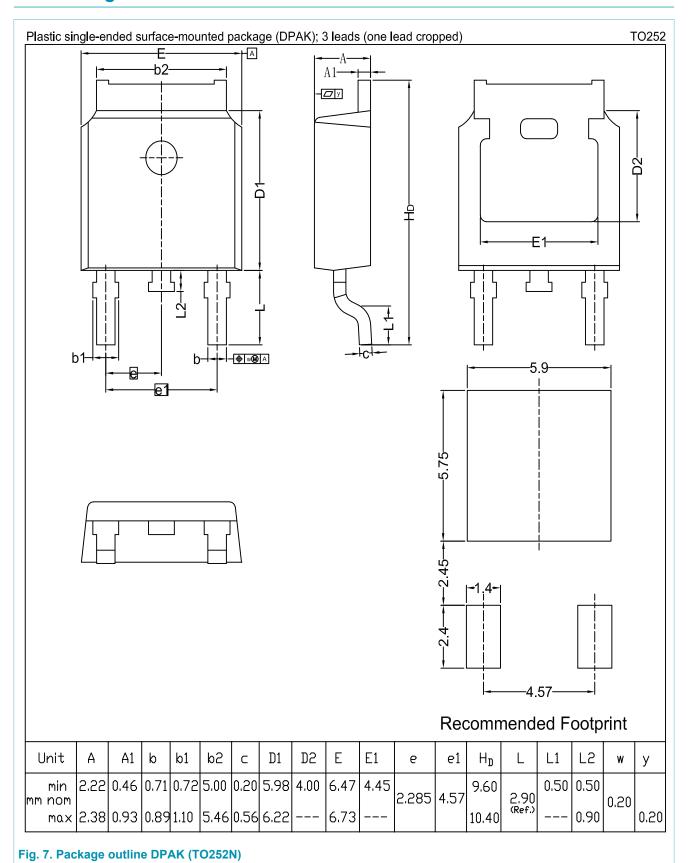


Fig. 6. Reverse recovery definitions; ramp recovery

## 10. Package outline



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# 11. Revision history

## Table 6. Revision history

Document ID	Date	Changes
BYV29FD-600 Rev.01	20110307	Initial release
BYV29FD-600 Rev.02	20170815	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of WeEn Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Update "Package outline" due to subcon transfer.</li> </ul>
BYV29FD-600 Rev.03	20171122	<ul> <li>Add version number and revision history on this datasheet.</li> <li>Update "SOT428" to "TO252" on "General description" section.</li> </ul>

### **Enhanced ultrafast power diode**

# 12. Legal information

### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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